

CentralTM Semiconductor Corp.

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Manufacturers of World Class Discrete Semiconductors

www.centrasemi.com

NPN	PNP
MPS6512	MPS6516
MPS6513	MPS6517
MPS6514	MPS6518
MPS6515	MPS6519

**COMPLEMENTARY
SILICON TRANSISTORS**

JEDEC TO-92 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR MPS6512 Series (NPN) and MPS6516 Series (PNP) types are molded Epoxy Silicon Small Signal Transistors designed for general-purpose amplifier applications.

MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

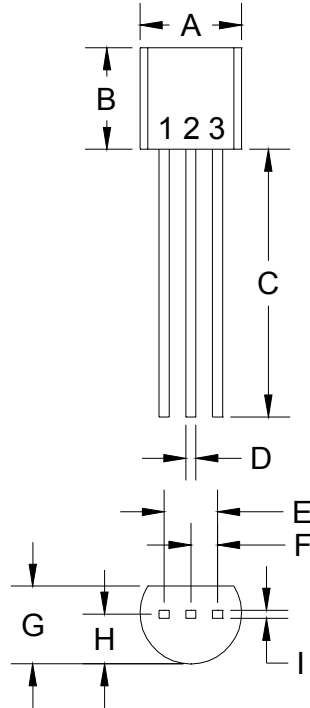
	<u>SYMBOL</u>	<u>MPS6512</u> <u>MPS6513</u>	<u>MPS6514</u> <u>MPS6515</u>	<u>MPS6516</u> <u>MPS6517</u> <u>MPS6518</u>	<u>MPS6519</u>	<u>UNITS</u>
Collector-Base Voltage	V_{CBO}	40	40	40	25	V
Collector-Emitter Voltage	V_{CEO}	30	25	40	25	V
Emitter-Base Voltage	V_{EBO}		4.0			V
Collector Current	I_C		100			mA
Power Dissipation	P_D		625			mW
Power Dissipation ($T_C=25^\circ\text{C}$)	P_D		1.5			W
Operating and Storage Junction Temperature	T_J, T_{stg}		-65 to +150			$^\circ\text{C}$
Thermal Resistance	θ_{JC}		83.3			$^\circ\text{C/W}$
Thermal Resistance	θ_{JA}		200			$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

<u>SYMBOL</u>	<u>TEST CONDITIONS</u>	<u>MPS6512</u> <u>MPS6513</u>		<u>MPS6514</u> <u>MPS6515</u>		<u>MPS6516</u> <u>MPS6517</u> <u>MPS6518</u>		<u>MPS6519</u>		<u>UNITS</u>
		<u>MIN</u>	<u>MAX</u>	<u>MIN</u>	<u>MAX</u>	<u>MIN</u>	<u>MAX</u>	<u>MIN</u>	<u>MAX</u>	
I_{CBO}	$V_{CB}=30\text{V}$		50		50		50		-	nA
I_{CBO}	$V_{CB}=20\text{V}$		-		-		-		50	nA
BV_{CEO}	$I_C=0.5\text{mA}$	30		25		40		25		V
BV_{EBO}	$I_E=10\mu\text{A}$	4.0		4.0		4.0		4.0		V
$V_{CE(SAT)}$	$I_C=50\text{mA}, I_B=5.0\text{mA}$		0.5		0.5		0.5		0.5	V
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=100\text{kHz}$		3.5		3.5		4.0		4.0	pF
<u>SYMBOL</u>	<u>TEST CONDITIONS</u>	<u>MPS6512</u> <u>MPS6516</u>		<u>MPS6513</u> <u>MPS6517</u>		<u>MPS6514</u> <u>MPS6518</u>		<u>MPS6515</u> <u>MPS6519</u>		
h_{FE}	$V_{CE}=10\text{V}, I_C=2.0\text{mA}$	50	100	90	180	150	300	250	500	
h_{FE}	$V_{CE}=10\text{V}, I_C=100\text{mA}$	30		60		90		150		

(Continued)

R0

TO-92 PACKAGE - MECHANICAL OUTLINE

R1

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

LEAD CODE

1. Emitter
2. Base
3. Collector

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